



PHKD6N02LT

Dual N-channel TrenchMOS logic level FET

Rev. 04 — 27 April 2010

Product data sheet

1. Product profile

1.1 General description

Dual logic level N-channel enhancement mode Field-Effect Transistor (FET) in a plastic package using TrenchMOS technology. This product is designed and qualified for use in computing, communications, consumer and industrial applications only.

1.2 Features and benefits

- Low conduction losses due to low on-state resistance
- Suitable for logic level gate drive sources

1.3 Applications

- Battery chargers
- DC-to-DC convertors
- Notebook computers
- Portable equipment

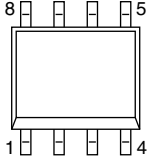
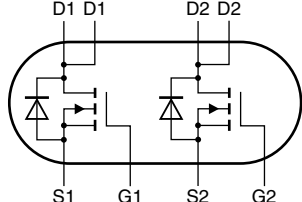
1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{DS}	drain-source voltage	$T_j \geq 25\text{ °C}$; $T_j \leq 150\text{ °C}$	-	-	20	V
I_D	drain current	$T_{sp} = 25\text{ °C}$; Single device conducting; see Figure 1 ; see Figure 3	-	-	10.9	A
P_{tot}	total power dissipation	$T_{sp} = 25\text{ °C}$; see Figure 2	-	-	4.17	W
Static characteristics						
$R_{DS(on)}$	drain-source on-state resistance	$V_{GS} = 2.5\text{ V}$; $I_D = 3\text{ A}$; $T_j = 25\text{ °C}$	-	25	35	m Ω
Dynamic characteristics						
Q_{GD}	gate-drain charge	$V_{GS} = 5\text{ V}$; $I_D = 6\text{ A}$; $V_{DS} = 16\text{ V}$; $T_j = 25\text{ °C}$; see Figure 11	-	6	-	nC

2. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S1	source1	 <p>SOT96-1 (SO8)</p>	 <p>mbk725</p>
2	G1	gate1		
3	S2	source2		
4	G2	gate2		
5	D2	drain2		
6	D2	drain2		
7	D1	drain1		
8	D1	drain1		

3. Ordering information

Table 3. Ordering information

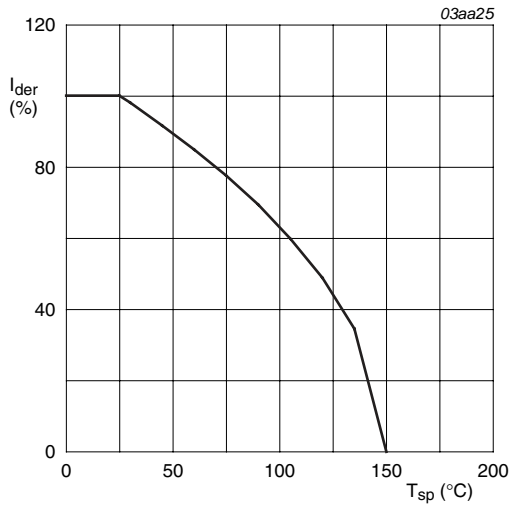
Type number	Package		
	Name	Description	Version
PHKD6N02LT	SO8	plastic small outline package; 8 leads; body width 3.9 mm	SOT96-1

4. Limiting values

Table 4. Limiting values

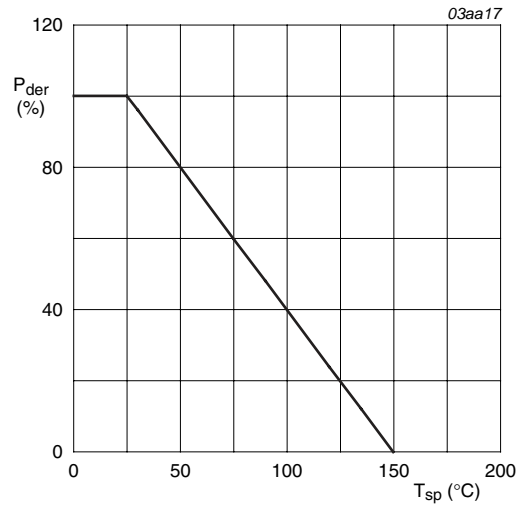
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{DS}	drain-source voltage	$T_j \geq 25\text{ °C}$; $T_j \leq 150\text{ °C}$	-	-	20	V
V_{DGR}	drain-gate voltage	$T_j \leq 150\text{ °C}$; $T_j \geq 25\text{ °C}$; $R_{GS} = 20\text{ k}\Omega$	-	-	20	V
V_{GS}	gate-source voltage		-12	-	12	V
I_D	drain current	$T_{sp} = 100\text{ °C}$; Single device conducting; see Figure 1	-	-	6.8	A
		$T_{sp} = 25\text{ °C}$; Single device conducting; see Figure 1 ; see Figure 3	-	-	10.9	A
I_{DM}	peak drain current	$T_{sp} = 25\text{ °C}$; $t_p \leq 100\text{ }\mu\text{s}$; pulsed; Single device conducting; see Figure 3	-	-	44	A
P_{tot}	total power dissipation	$T_{sp} = 25\text{ °C}$; see Figure 2	-	-	4.17	W
T_{stg}	storage temperature		-55	-	150	°C
T_j	junction temperature		-55	-	150	°C
Source-drain diode						
I_S	source current	$T_{sp} = 25\text{ °C}$	-	-	3.5	A
I_{SM}	peak source current	$T_{sp} = 25\text{ °C}$; $t_p \leq 10\text{ }\mu\text{s}$; pulsed	-	-	44	A



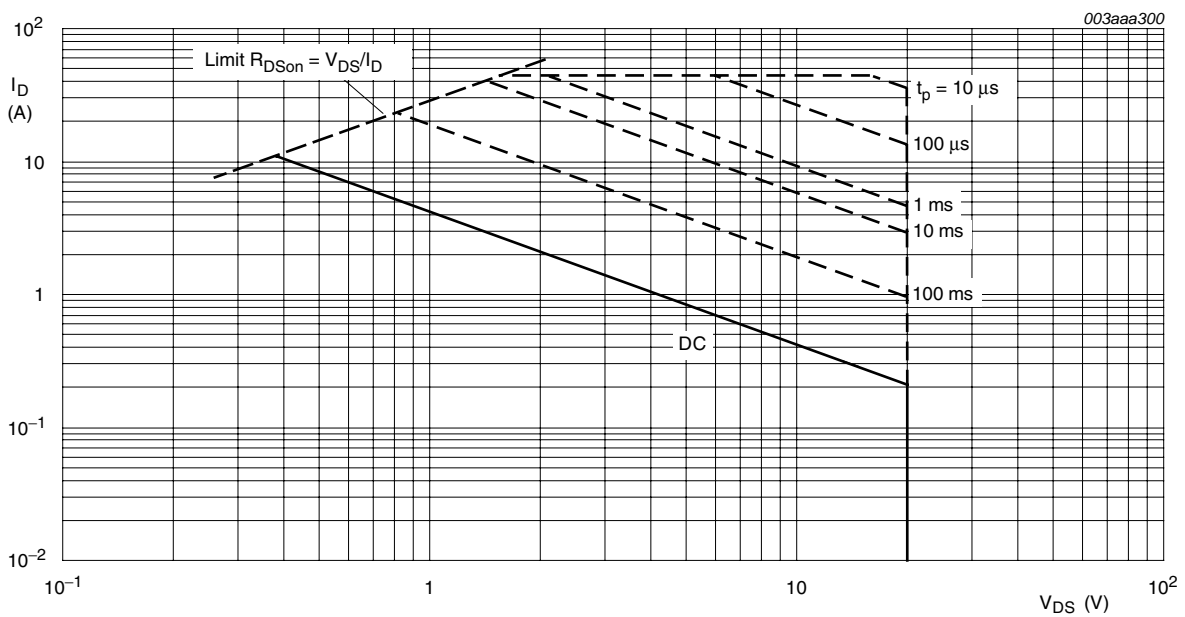
$$I_{der} = \frac{I_D}{I_{D(25^\circ\text{C})}} \times 100\%$$

Fig. 1. Normalized continuous drain current as a function of solder point temperature



$$P_{der} = \frac{P_{tot}}{P_{tot(25^\circ\text{C})}} \times 100\%$$

Fig. 2. Normalized total power dissipation as a function of solder point temperature



$T_{sp} = 25^\circ\text{C}; I_{DM}$ is single pulse;

Fig. 3. Safe operating area; continuous and peak drain currents as a function of drain-source voltage

5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j-sp)}$	thermal resistance from junction to solder point	see Figure 4	-	-	30	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient	minimum footprint; mounted on printed-circuit board	-	70	-	K/W

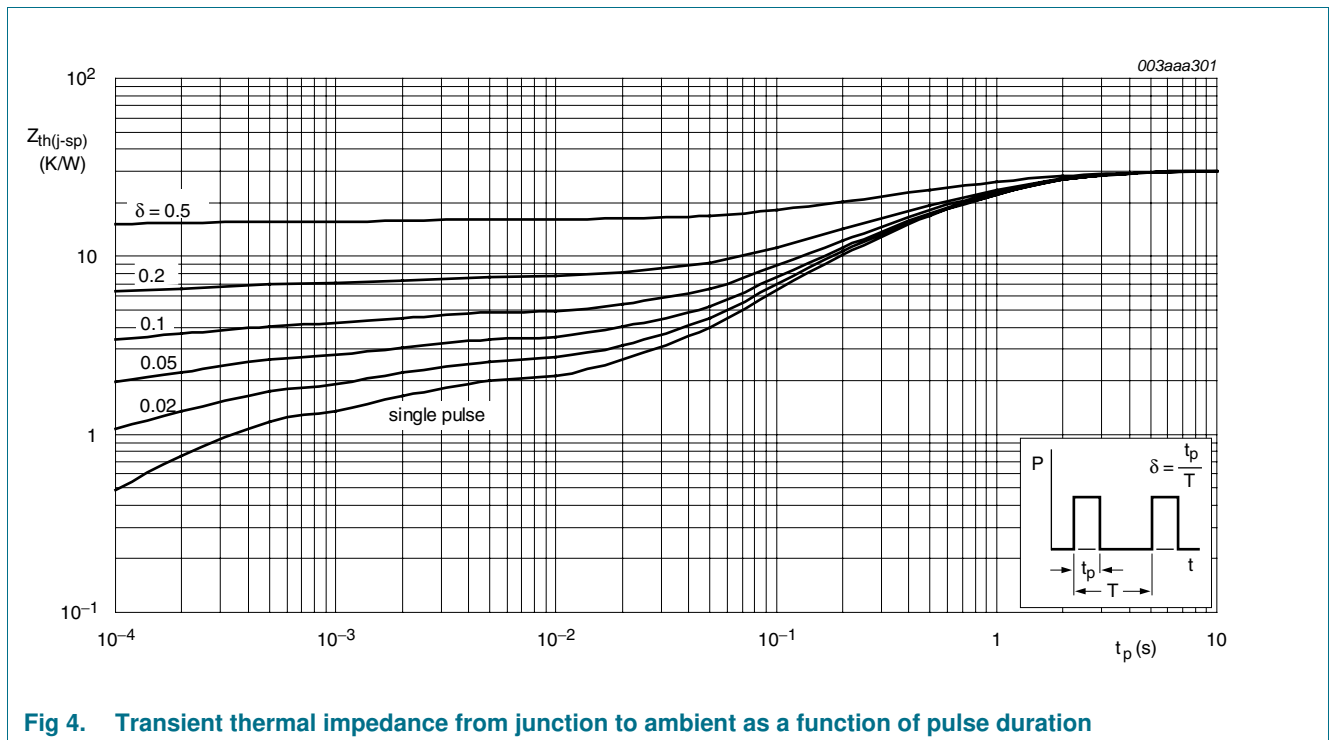


Fig 4. Transient thermal impedance from junction to ambient as a function of pulse duration

6. Characteristics

Table 6. Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Static characteristics						
$V_{(BR)DSS}$	drain-source breakdown voltage	$I_D = 250 \mu\text{A}$; $V_{GS} = 0 \text{ V}$; $T_j = 25 \text{ }^\circ\text{C}$	20	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	$I_D = 250 \mu\text{A}$; $V_{DS} = 10 \text{ V}$; $T_j = 25 \text{ }^\circ\text{C}$; see Figure 8	0.5	-	1.5	V
I_{DSS}	drain leakage current	$V_{DS} = 20 \text{ V}$; $V_{GS} = 0 \text{ V}$; $T_j = 25 \text{ }^\circ\text{C}$	-	0.05	10	μA
		$V_{DS} = 20 \text{ V}$; $V_{GS} = 0 \text{ V}$; $T_j = 150 \text{ }^\circ\text{C}$	-	-	500	μA
I_{GSS}	gate leakage current	$V_{GS} = 12 \text{ V}$; $V_{DS} = 0 \text{ V}$; $T_j = 25 \text{ }^\circ\text{C}$	-	-	100	nA
		$V_{GS} = -12 \text{ V}$; $V_{DS} = 0 \text{ V}$; $T_j = 25 \text{ }^\circ\text{C}$	-	-	100	nA
$R_{DS(on)}$	drain-source on-state resistance	$V_{GS} = 2.5 \text{ V}$; $I_D = 3 \text{ A}$; $T_j = 25 \text{ }^\circ\text{C}$	-	25	35	m Ω
		$V_{GS} = 5 \text{ V}$; $I_D = 3 \text{ A}$; $T_j = 150 \text{ }^\circ\text{C}$; see Figure 9 ; see Figure 10	-	-	35	m Ω
		$V_{GS} = 5 \text{ V}$; $I_D = 3 \text{ A}$; $T_j = 25 \text{ }^\circ\text{C}$; see Figure 9 ; see Figure 10	-	16	20	m Ω
Dynamic characteristics						
$Q_{G(tot)}$	total gate charge	$I_D = 6 \text{ A}$; $V_{DS} = 16 \text{ V}$; $V_{GS} = 5 \text{ V}$; $T_j = 25 \text{ }^\circ\text{C}$; see Figure 11	-	15.3	-	nC
Q_{GS}	gate-source charge		-	2.2	-	nC
Q_{GD}	gate-drain charge		-	6	-	nC
C_{iss}	input capacitance	$V_{DS} = 10 \text{ V}$; $V_{GS} = 0 \text{ V}$; $f = 1 \text{ MHz}$; $T_j = 25 \text{ }^\circ\text{C}$; see Figure 12	-	950	-	pF
C_{oss}	output capacitance		-	355	-	pF
C_{riss}	reverse transfer capacitance		-	256	-	pF
$t_{d(on)}$	turn-on delay time	$V_{DS} = 10 \text{ V}$; $R_L = 3.3 \Omega$; $V_{GS} = 5 \text{ V}$; $R_{G(ext)} = 4.7 \Omega$; $T_j = 25 \text{ }^\circ\text{C}$	-	15	-	ns
t_r	rise time		-	49	-	ns
$t_{d(off)}$	turn-off delay time		-	50	-	ns
t_f	fall time		-	23	-	ns
Source-drain diode						
V_{SD}	source-drain voltage	$I_S = 6 \text{ A}$; $V_{GS} = 0 \text{ V}$; $T_j = 25 \text{ }^\circ\text{C}$; see Figure 13	-	-	1.2	V
t_{rr}	reverse recovery time	$I_S = 6 \text{ A}$; $dI_S/dt = -100 \text{ A}/\mu\text{s}$; $V_{GS} = 0 \text{ V}$;	-	40	-	ns
Q_r	recovered charge	$V_{DS} = 20 \text{ V}$; $T_j = 25 \text{ }^\circ\text{C}$	-	7	-	nC

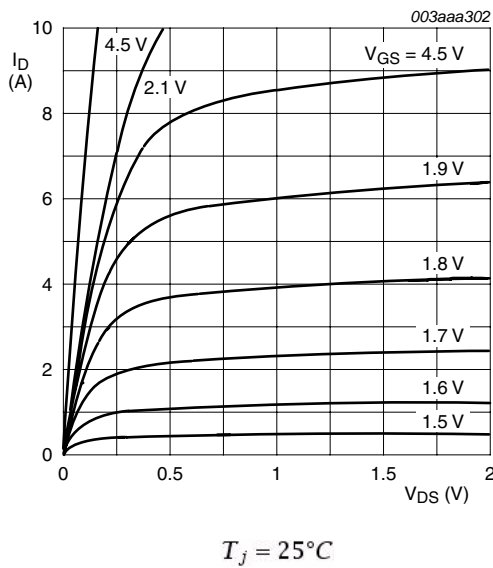


Fig 5. Output characteristics: drain current as a function of drain-source voltage; typical values

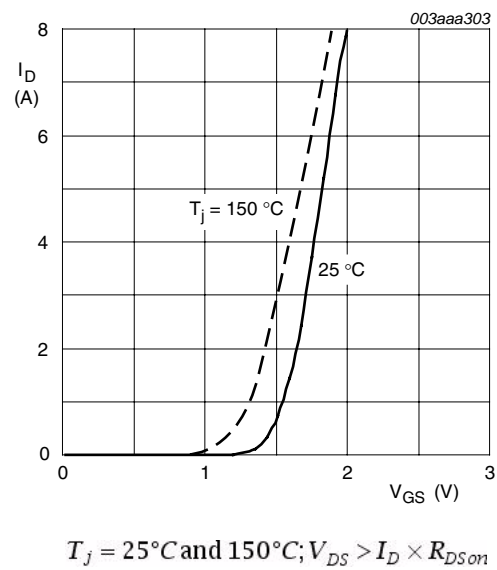


Fig 6. Transfer characteristics: drain current as a function of gate-source voltage; typical values

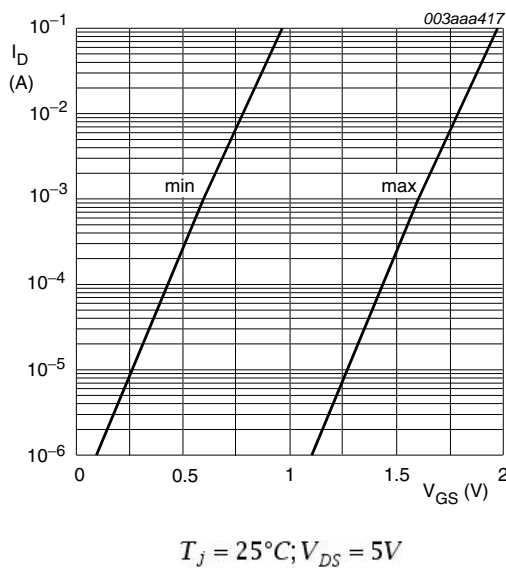


Fig 7. Sub-threshold drain current as a function of gate-source voltage

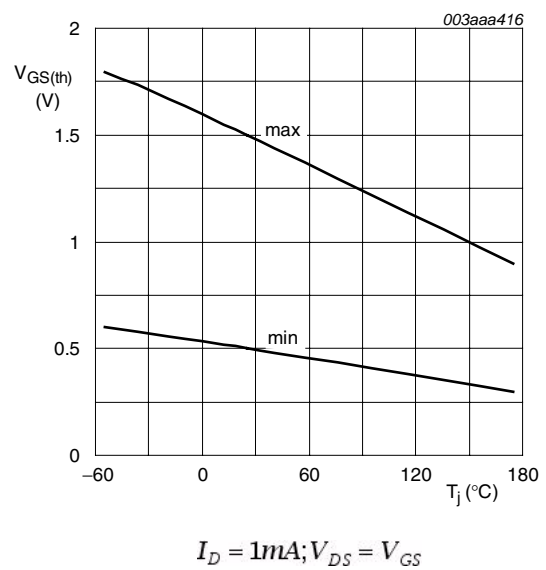
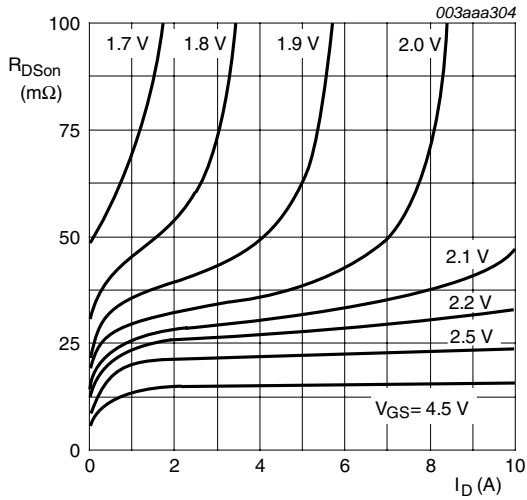
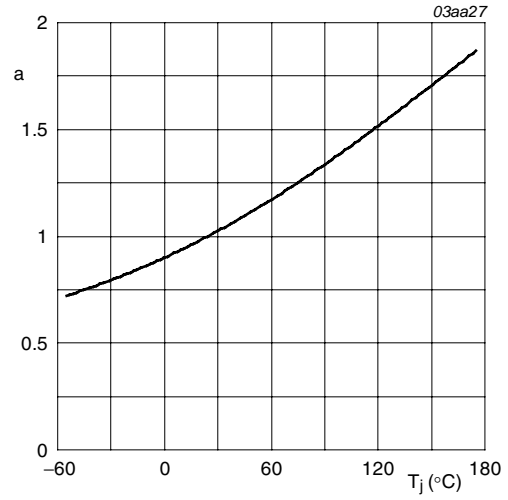


Fig 8. Gate-source threshold voltage as a function of junction temperature



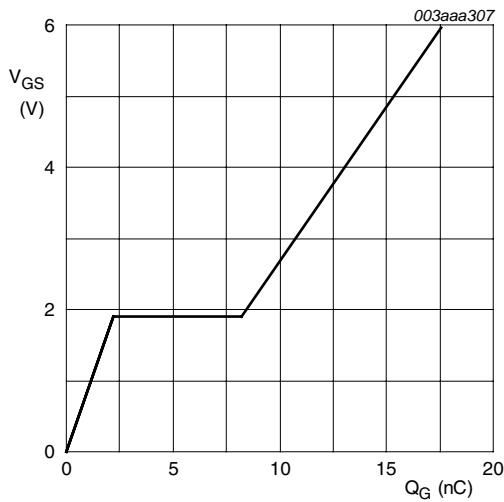
$T_j = 25^\circ\text{C}$

Fig 9. Drain-source on-state resistance as a function of drain current; typical values



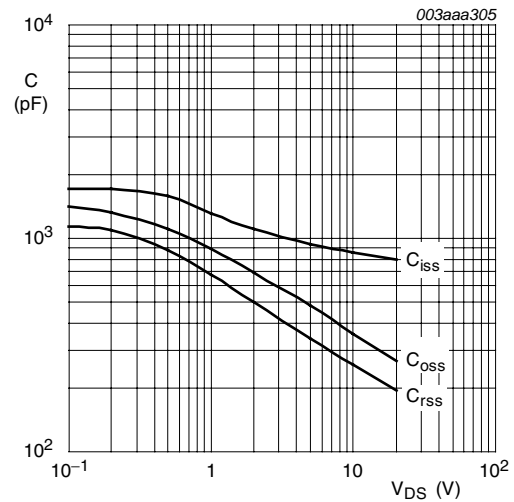
$$a = \frac{R_{DS(on)}}{R_{DS(on)@25^\circ\text{C}}}$$

Fig 10. Normalized drain-source on-state resistance factor as a function of junction temperature



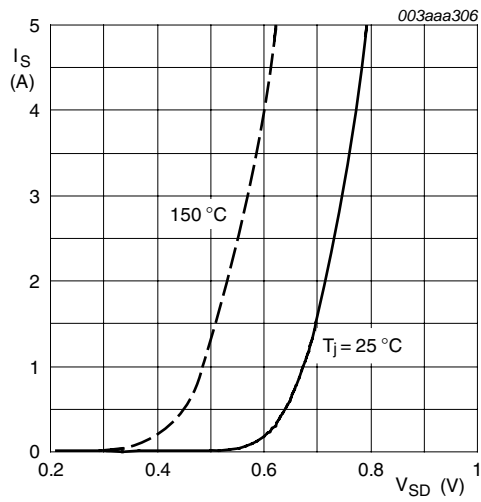
$I_D = 6\text{A}; V_{DD} = 16\text{V}$

Fig 11. Gate-source voltage as a function of gate charge; typical values



$V_{GS} = 0\text{V}; f = 1\text{MHz}$

Fig 12. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values



$T_j = 25^\circ\text{C}$ and $150^\circ\text{C}; V_{GS} = 0\text{V}$

Fig 13. Source current as a function of source-drain voltage; typical values

7. Package outline

SO8: plastic small outline package; 8 leads; body width 3.9 mm

SOT96-1

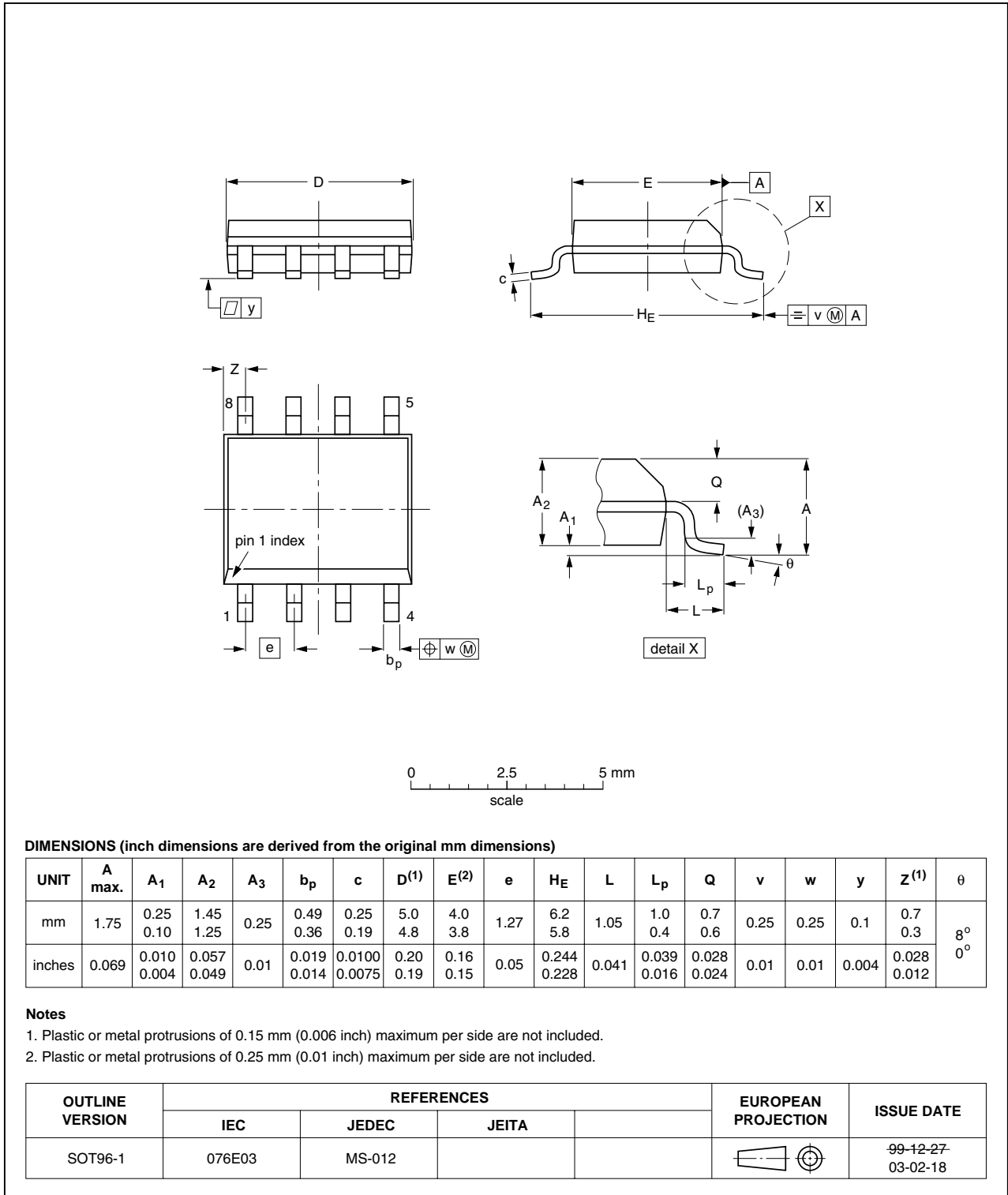


Fig 14. Package outline SOT96-1 (SO8)

8. Revision history

Table 7. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PHKD6N02LT_4	20100427	Product data sheet	-	PHKD6N02LT_3
Modifications:	• Various changes to content.			
PHKD6N02LT_3	20091119	Product data sheet	-	PHKD6N02LT-02
PHKD6N02LT-02	20030812	Product data	-	PHKD6N02LT-01
PHKD6N02LT-01	20010907	Product data	-	-

9. Legal information

9.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nexperia.com>.

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